

What Can We Learn form the IPod/iPhone Revolution

Gregory A. Quirk
Technical Marketing Manager
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Samsung 65nm 8Gb MLC NAND Flash

- Uses exact same memory as 8GB nano
- Expected to see 51nm (most advanced)
 - Over surplus of 65nm parts
- Samsung is the primary supplier
 - Secondary suppliers (Toshiba)



Infineon PMB8876 S-GOLD 2

- EDGE and baseband processor
- Approximately 780KB of embedded memory
- 130nm process technology
- 2004 Date Code



Why Brand Components

- System claims
- Bill of Materials
- Counterfeiting



Next Generation Expectations

- Memory
 - Samsung 51nm 16Gb MLC NAND Flash
 - Low power consumption
 - Higher density
 - Reduced cost
- Baseband
 - Will likely be someone else to expand into global market (3G?)
 - Qualcomm